

US3A THRU US3M
High Efficiency Rectifier



Voltage: 50~1000 Volts

Current: 3.0 Amperes

Package: SMC

Features

- NH'S High Efficiency Rectifier Chip Technology
- Low Switching Loss For High Efficiency
- Low Leakage Current For High Reliability
- Ultra Fast Switching Speed

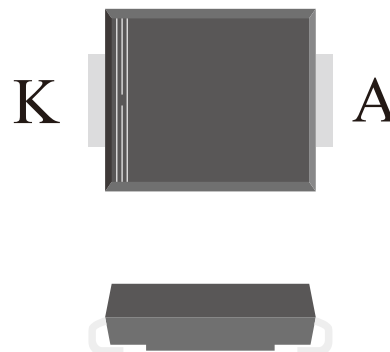
Mechanical Data

- **Case:** Molded With UL-94 ClassV-0 Recognized, RoHS-Compliant
- **Polarity:** Look At The Diagram And Polarity On The Right
- **Terminals:** Tin Plated Leads,Solderable Per J-STD-002 And JESD22-B102

Typical Applications

- Switch Mode Power Supplies (SMPS)
- Fast Chargers
- LED Driver And Monitor Lighting
- Automotive Electronics And Charging Posts

Diagram:



Polarity:



Single Phase,Half Wave,60Hz,Resistive Or Inductive Load.For Capacitive Load,Derate Current By 20%

Maximum Ratings (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	US 3A	US 3B	US 3D	US 3G	US 3J	US 3K	US 3M	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltag		V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		$I_{F(AV)}$	3.0							A
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I_{FSM}	100							A
Current Squared Time	$t < 8.3ms$	I^2t	41.5							A ² sec

Electrical Characteristics (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	US 3A	US 3B	US 3D	US 3G	US 3J	US 3K	US 3M	Unit
Maximum Instantaneous Forward Voltage	I _F = 3.0 A	V _F	1.0			1.3	1.7			V
Maximum DC Reverse Current at Rated DC Blocking Voltage	Ta=25℃ ,V _R =VRRM Ta=125℃ ,V _R =VRRM*80%	I _{RRM}	5 200							uA uA
Typical Junction Capacitance	4 V,1MHz	C _J	30			18	12			pF
Maximum Reverse Recovery Time	IF=0.5A, IR=1.0A, IRR=0.25A	Trr	50				75			nS

Thermal Characteristics (Ta=25°C Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	US 3A	US 3B	US 3D	US 3G	US 3J	US 3K	US 3M	Unit
Operating Junction Temperature Range		T _J	-55~150							℃
Storage Temperature Range		T _{STD}	-55~150							
Thermal Resistance Junction To Ambient With Steady-State	Still Air Environment With Ta=25℃	R _{θJA}	55.0							℃/W
Thermal Resistance Junction-Case With Steady-State	Device Mounted On 1 in2 FR-4 Board With 2oz. Copper	R _{θJC}	15.0							

Notes: 1.Pulse Test: 300 Us Pulse Width,1% Duty Cycle

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Typical Characteristics Curves

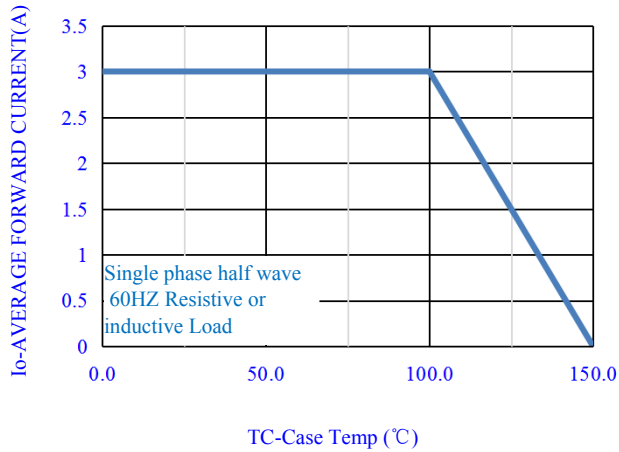


Fig.1-FORWARD CURRENT DERATING CURVE

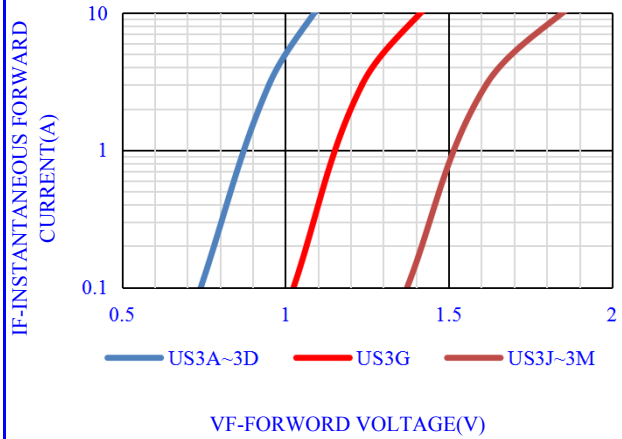


Fig.2- TYPICAL INSTANTANEOUS FORWARD

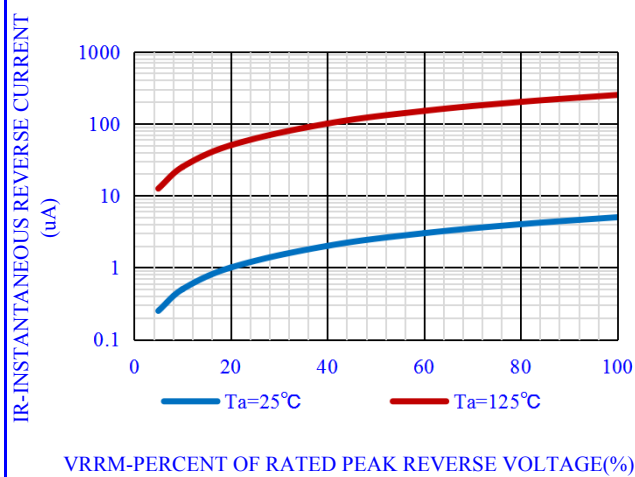


Fig.3- TYPICAL REVERSE CHARACTERISTICS

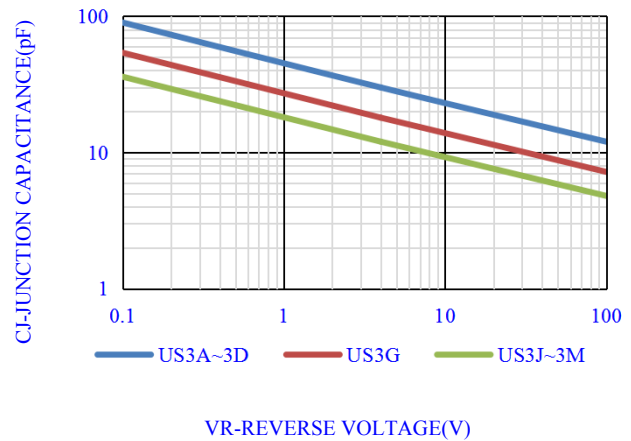


Fig.4- TYPICAL JUNCTION CAPACITANCE

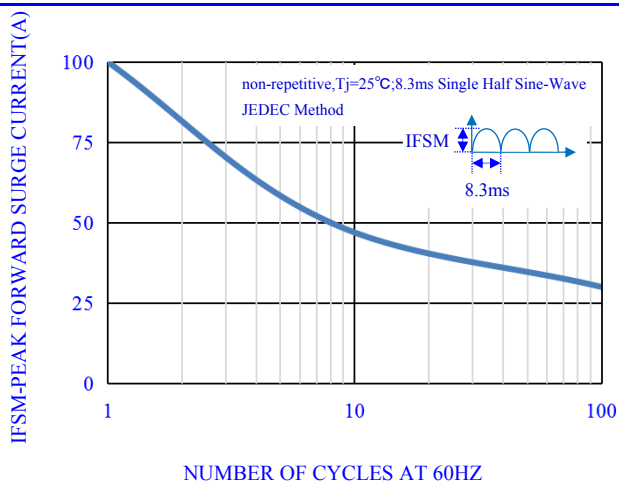


Fig.5-MAX. NON-REPETITIVE SURGE CURRENT

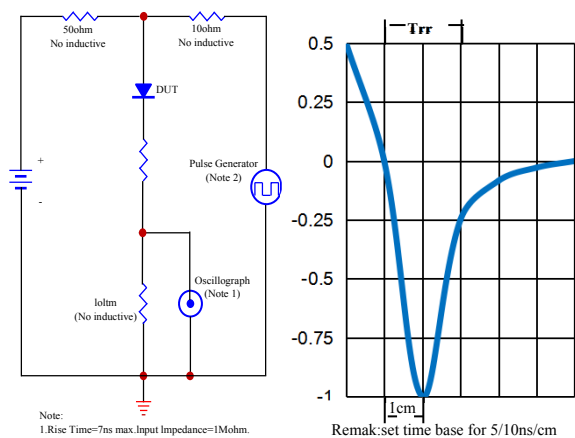
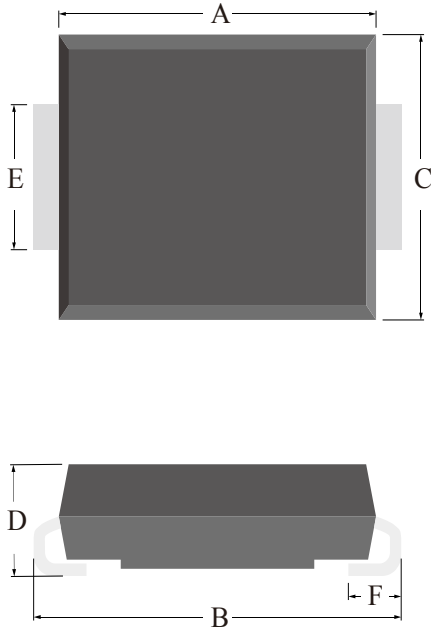


Fig.6-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT

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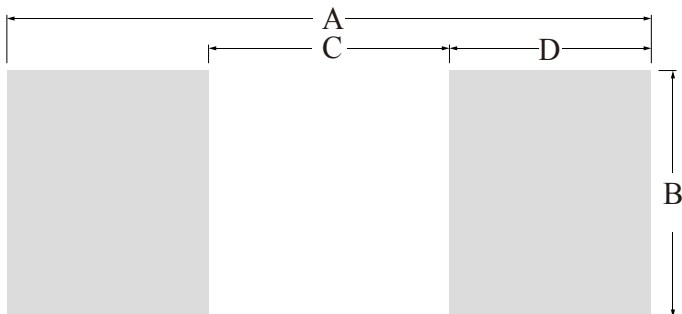
OUTLINE DRAWINGS



SMC

OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.60	-	7.11	0.2598	-	0.2799
B	7.75	-	8.13	0.3051	-	0.3201
C	5.59	-	6.22	0.2201	-	0.2449
D	2.00	-	2.62	0.0787	-	0.1031
E	2.75	-	3.25	0.1083	-	0.1280
F	0.76	-	1.52	0.0299	-	0.0598

RECOMMEDND LAYOUT DRAWINGS



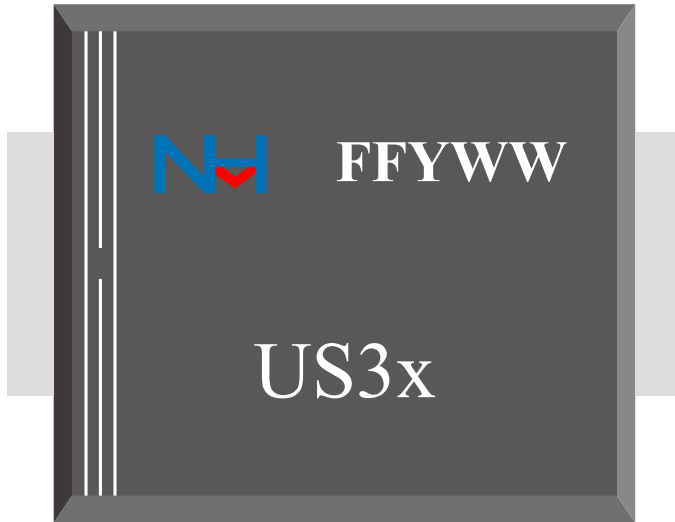
SMC

OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	9.90	-	-	0.3898	-
B	-	3.82	-	-	0.1504	-
C	-	3.84	-	-	0.1512	-
D	-	3.03	-	-	0.1193	-

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MARKING



MARKING INSTRUCTION

NH=Niuhan Trademark

FF=Product Line Code,According To Actual Changes

YWW=Date Code,According To Actual Changes

US3x=Model,x=A,B,D,G,J,K,M

White band denotes cathode

PACKING INFORMATION

Package Type	Package Code	Product Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)
SMC	P1	0.254	13" Reel	3000	6000	48000
SMC	P2	0.254	13" Reel	3000	6000	60000

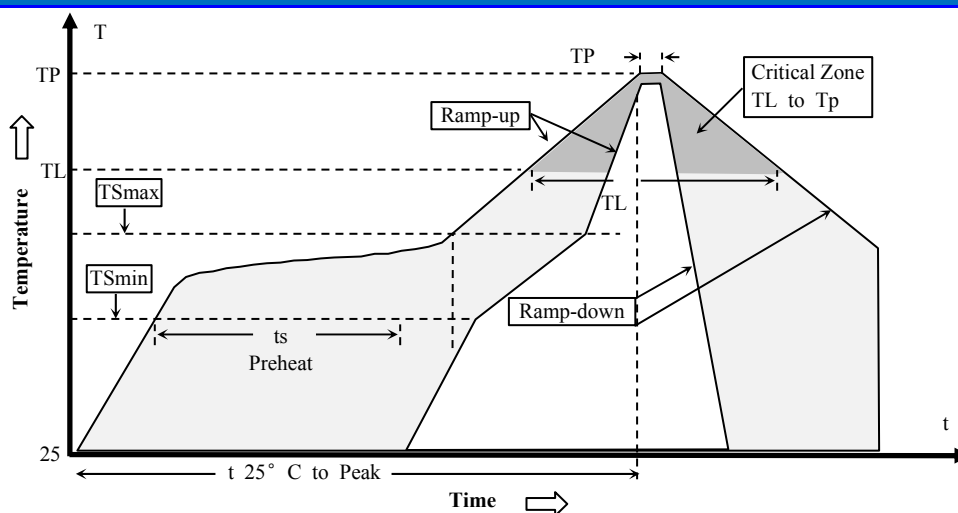
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(T _S min) -Temperature Max(T _S max) -Time(t _s min to t _s max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T _p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

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